

CMPA901A035F

35 W, 9.0 - 11.0 GHz, GaN MMIC, Power Amplifier

Description

The CMPA901A035F is a gallium nitride (GaN) high electron mobility transistor (HEMT) based monolithic microwave integrated circuit (MMIC) on a silicon carbide (SiC) substrate. The semiconductor offers 35 Watts of power from 9 to 11 GHz of instantaneous bandwidth. The GaN HEMT MMIC is housed in a thermally-enhanced, 10-lead 25 mm x 9.9 mm metal/ceramic flanged package. It offers high gain and superior efficiency in a small footprint package at 50 ohms.



Package Types: 440213 PN's: CMPA901A035F

Features

- 35 W typical P_{SAT}
- >33% typical power added efficiency
- 22.5 dB large signal gain
- High temperature operation

Note:

Features are typical performance across frequency under 25 °C operation. Please reference performance charts for additional details.

Typical Performance Over 9.0 - 11.0 GHz ($T_c = 25 \text{ °C}$)

Parameter	9.0 GHz	9.5 GHz	10.0 GHz	10.5 GHz	11.0 GHz	Units
Small Signal Gain ^{1, 2}	34.8	32.4	32.7	33.2	32.6	dB
Output Power ^{1, 3}	45.9	45.8	45.6	45.6	45.4	dBm
Power Gain ^{1, 3}	22.9	22.8	22.6	22.6	22.4	dB
Power Added Efficiency ^{1, 3}	37	34	33	33	34	%

Applications

Military radar

Marine radar

Weather radar

Medical applications

Notes:

1

 $^{1}V_{DD} = 28 \text{ V}, \text{ I}_{DQ} = 1500 \text{ mA.}$ 2 Measured at P_{IN} = -20 dBm. 3 Measured at P_{IN} = 23 dBm and 300 µs; duty cycle = 20%.



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Absolute Maximum Ratings (Not Simultaneous) at 25 °C

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	V _{DSS}	84	V _{DC}	25 °C
Gate-Source Voltage	V _{GS}	-10, +2	V _{DC}	25 °C
Storage Temperature	T _{stg}	-40, +150	°C	
Maximum Forward Gate Current	ا _G	19	mA	25 °C
Maximum Drain Current	I _{DMAX}	5	A	
Soldering Temperature	T _s	260	°C	
Junction Temperature	T,	225	°C	MTTF > 1e6 Hours

Electrical Characteristics (Frequency = 9.0 GHz to 11.0 GHz Unless Otherwise Stated; $T_c = 25$ °C)

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions
DC Characteristics	•					
Gate Threshold Voltage	V _{GS(th)}	-3.8	-2.8	-2.3	V	$V_{\rm DS} = 10 \text{ V}, I_{\rm D} = 19.8 \text{ mA}$
Gate Quiescent Voltage	V _{GS(Q)}	-	-2.7	-	V _{DC}	$V_{_{DD}}$ = 28 V, I $_{_{DQ}}$ = 1500 mA
Saturated Drain Current ¹	I _{DS}	14.3	19.8	-	А	$V_{\rm DS} = 6.0 \text{ V}, V_{\rm GS} = 2.0 \text{ V}$
Drain-Source Breakdown Voltage	V _{BD}	84	-	-	V	$V_{gs} = -8 V, I_{p} = 19.8 mA$
RF Characteristics ²						
Small Signal Gain	S21	-	34	-	dB	P _{IN} = -23 dBm, Freq = 9.0 - 10.0 GHz
Output Power	P _{OUT1}	_	45.7	_	dBm	$V_{DD} = 28 \text{ V}, \text{ I}_{DQ} = 1500 \text{ mA}, \text{ P}_{IN} = 23 \text{ dBm},$ Freq = 9.0 GHz
Output Power	P _{OUT2}	-	44.7	-	dBm	$V_{_{DD}} = 28 \text{ V}, \text{ I}_{_{DQ}} = 1500 \text{ mA}, \text{ P}_{_{IN}} = 23 \text{ dBm},$ Freq = 10.0 GHz
Power Added Efficiency	PAE ₁	-	40	-	%	$V_{DD} = 28 \text{ V}, \text{ I}_{DQ} = 1500 \text{ mA}, \text{ P}_{IN} = 23 \text{ dBm},$ Freq = 9.0 GHz
Power Added Efficiency	PAE ₂	-	37	-	%	$V_{DD} = 28 \text{ V}, \text{ I}_{DQ} = 1500 \text{ mA}, \text{ P}_{IN} = 23 \text{ dBm},$ Freq = 10.0 GHz
Input Return Loss	S11	-	-6.4	-	dB	P _{IN} = -23 dBm, 9.0 - 10.0 GHz
Output Return Loss	S22	_	-6.8	-	dB	P _{IN} = -23 dBm, 9.0 - 10.0 GHz
Output Mismatch Stress	VSWR	-	5:1	-	Ψ	No Damage at All Phase Angles

Notes:

¹ Scaled from PCM data.

 2 Unless otherwise noted: Pulse width = 300 $\mu s,$ duty cycle = 20%.

Thermal Characteristics

Parameter	Symbol	Rating	Units	Conditions	
Operating Junction Temperature	T	159	°C	Pulse Width = 300 μs, Duty Cycle = 20% P _{DISS} = 80 W, T _{CASE} = 85 °C	
Thermal Resistance, Junction to Case	R _{θJC}	0.93	°C/W		
Operating Junction Temperature	T	217	°C	- P _{DISS} = 80 W, T _{CASE} = 85 °C	
Thermal Resistance, Junction to Case	R _{θJC}	1.66	°C/W		

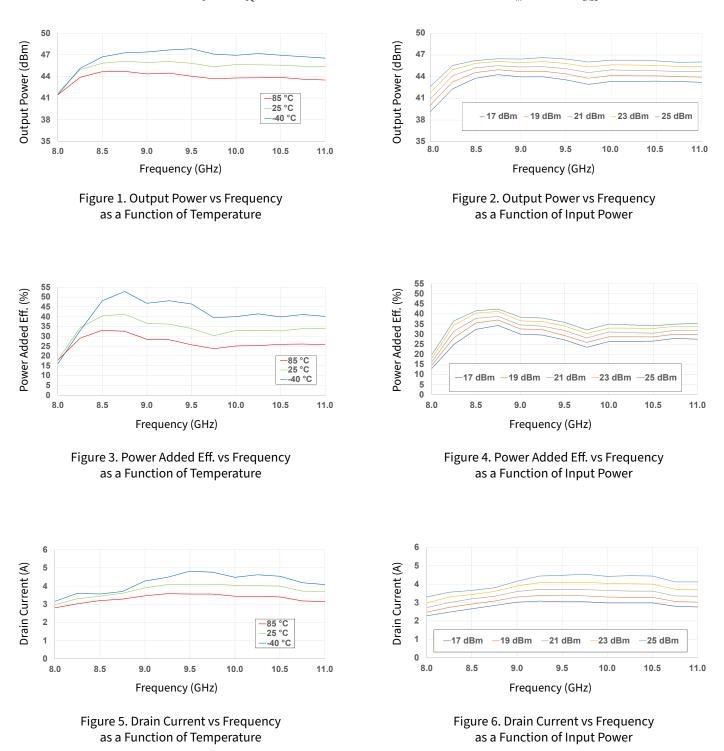
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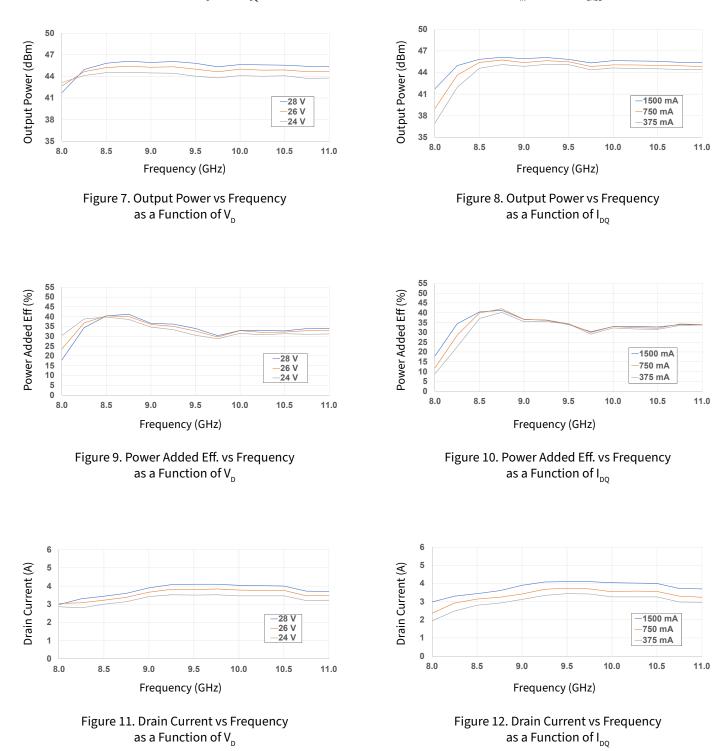
Test conditions unless otherwise noted: $V_D = 28 V$, $I_{DO} = 1500 mA$, pulse width = 300 μ s, duty cycle = 20%, $P_{IN} = 23 dBm$, $T_{BASE} = +25 °C$



³



Test conditions unless otherwise noted: $V_D = 28 V$, $I_{DO} = 1500 mA$, pulse width = 300 μ s, duty cycle = 20%, $P_{IN} = 23 dBm$, $T_{BASE} = +25 °C$



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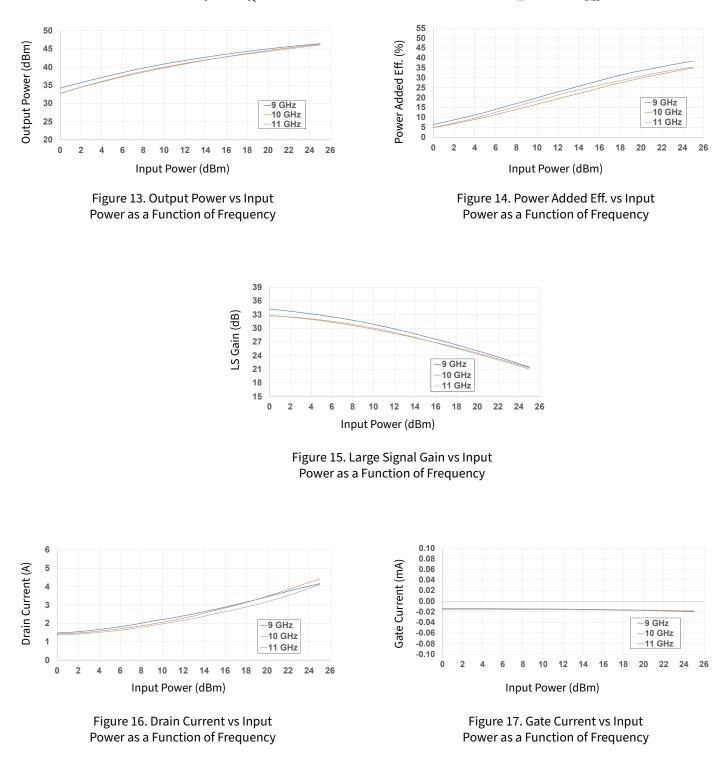
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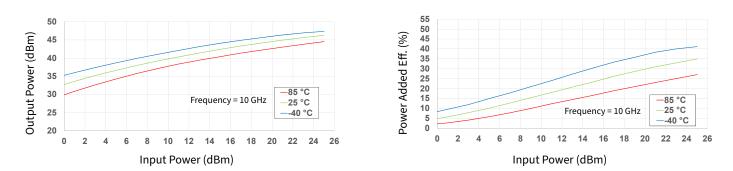
Typical Performance of the CMPA901A035F

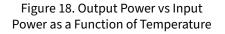
Test conditions unless otherwise noted: $V_{D} = 28 \text{ V}$, $I_{DO} = 1500 \text{ mA}$, pulse width = 300 μ s, duty cycle = 20%, $P_{IN} = 23 \text{ dBm}$, $T_{BASE} = +25 \text{ °C}$

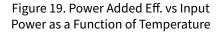


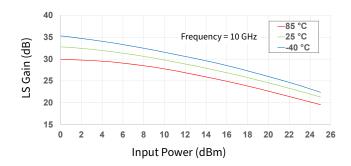


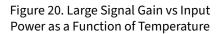
Test conditions unless otherwise noted: $V_{D} = 28 V$, $I_{DO} = 1500 mA$, pulse width = 300 μ s, duty cycle = 20%, $P_{IN} = 23 dBm$, $T_{BASE} = +25 °C$

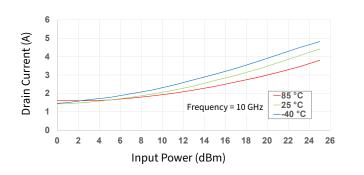


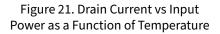












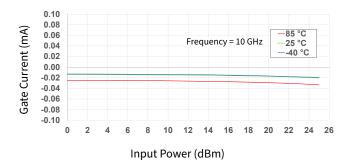


Figure 22. Gate Current vs Input Power as a Function of Temperature

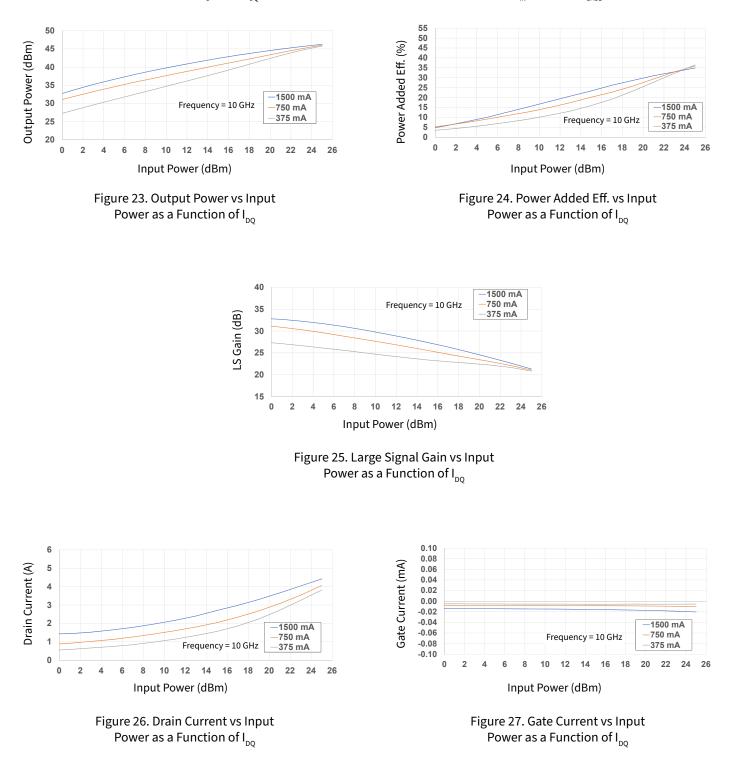
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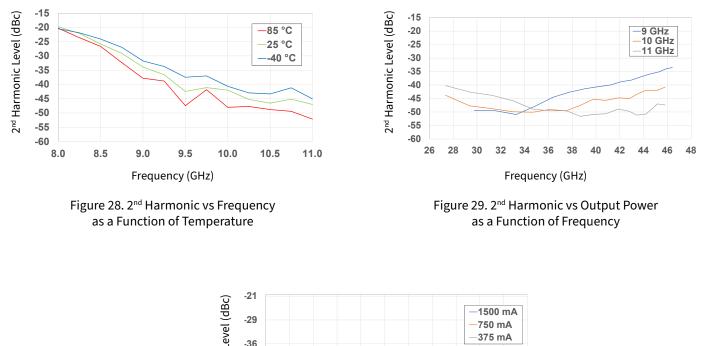
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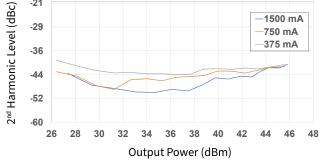
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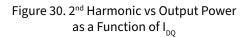


Typical Performance of the CMPA901A035F

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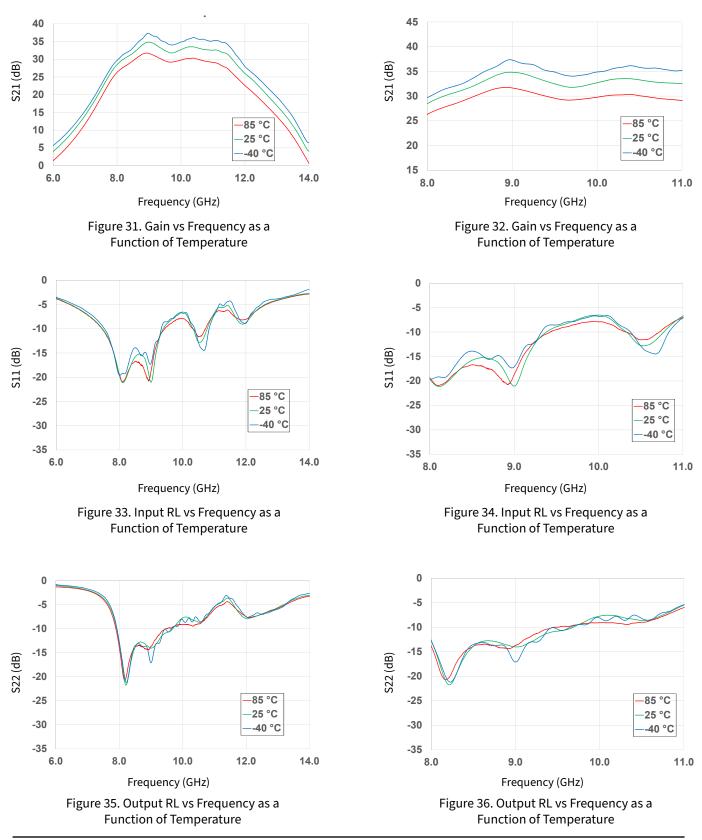




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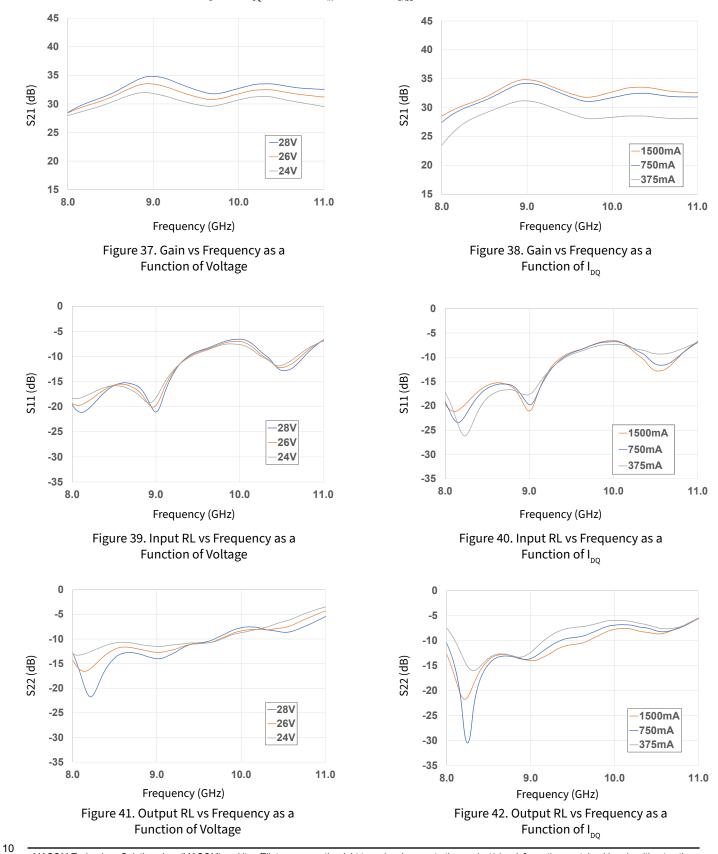
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Test conditions unless otherwise noted: $V_D = 28 \text{ V}$, $I_{DO} = 1500 \text{ mA}$, $P_{IN} = -20 \text{ dBm}$, $T_{BASE} = +25 \text{ °C}$

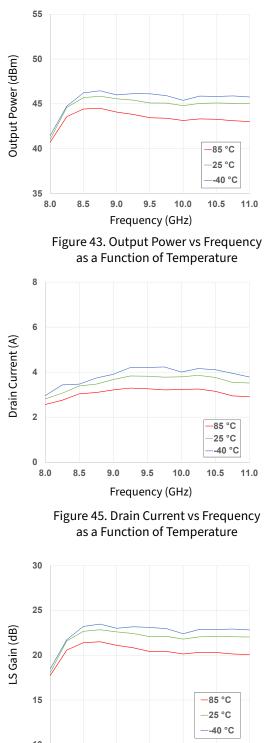


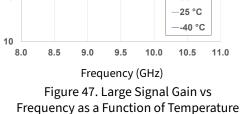
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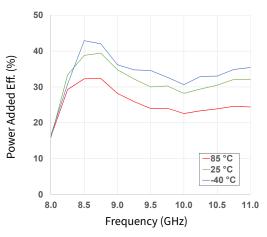


Figure 44. Power Added Eff. vs Frequency as a Function of Temperature

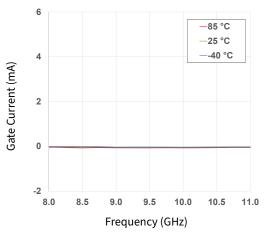
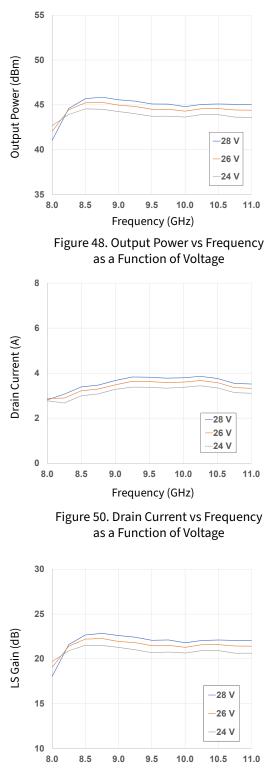


Figure 46. Gate Current vs Frequency as a Function of Temperature



Test conditions unless otherwise noted: $V_D = 28 V$, $I_{DO} = 1500 mA$, CW, $P_{IN} = 23 dBm$, $T_{BASE} = +25 °C$



Frequency (GHz) Figure 52. Large Signal Gain vs Frequency as a Function of Voltage

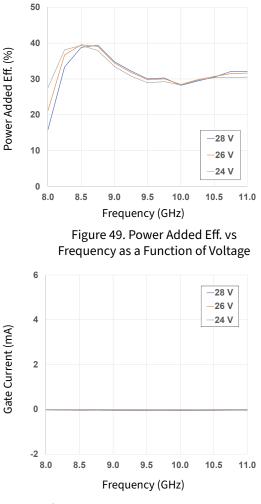
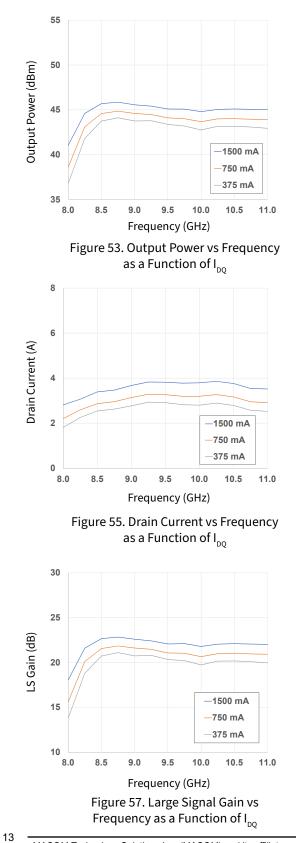


Figure 51. Gate Current vs Frequency as a Function of Voltage



Test conditions unless otherwise noted: V_D = 28 V, I_{DQ} = 1500 mA, CW, P_{IN} = 23 dBm, T_{BASE} = +25 °C



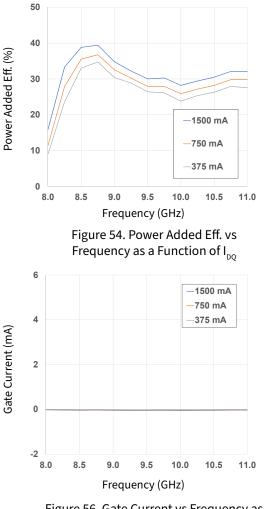
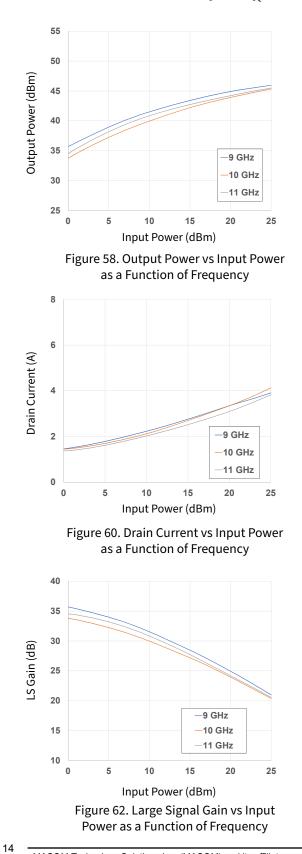
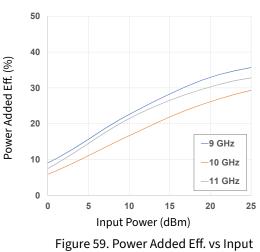


Figure 56. Gate Current vs Frequency as a Function of I_{DO}



Test conditions unless otherwise noted: $V_D = 28 \text{ V}$, $I_{DO} = 1500 \text{ mA}$, CW, $P_{IN} = 23 \text{ dBm}$, Frequency = 10 GHz, $T_{BASE} = +25 \text{ °C}$





Power as a Function of Frequency

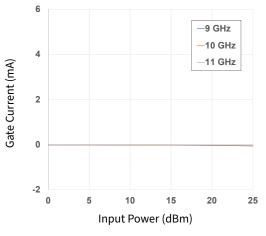


Figure 61. Gate Current vs Input Power as a Function of Frequency

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Test conditions unless otherwise noted: $V_D = 28 \text{ V}$, $I_{DO} = 1500 \text{ mA}$, CW, $P_{IN} = 23 \text{ dBm}$, Frequency = 10 GHz, $T_{BASE} = +25 \text{ °C}$

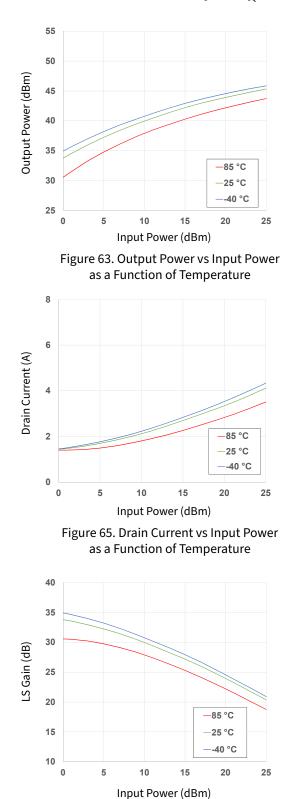


Figure 67. Large Signal Gain vs Input Power as a Function of Temperature

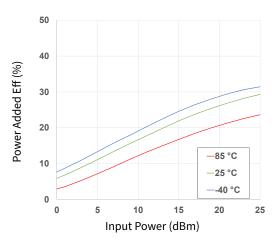


Figure 64. Power Added Eff. vs Input Power as a Function of Temperature

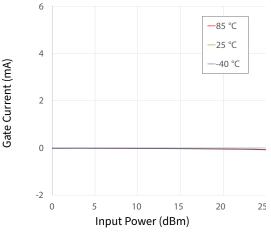
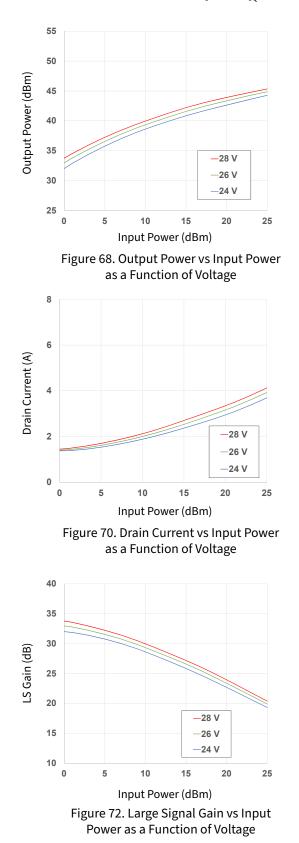


Figure 66. Gate Current vs Input Power as a Function of Temperature



Test conditions unless otherwise noted: $V_D = 28 \text{ V}$, $I_{DO} = 1500 \text{ mA}$, CW, $P_{IN} = 23 \text{ dBm}$, Frequency = 10 GHz, $T_{BASE} = +25 \text{ °C}$



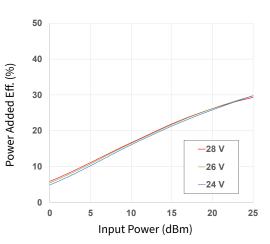


Figure 69. Power Added Eff. vs Input Power as a Function of Voltage

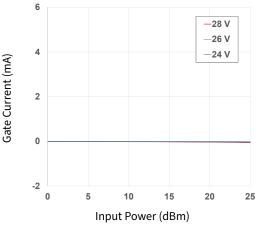
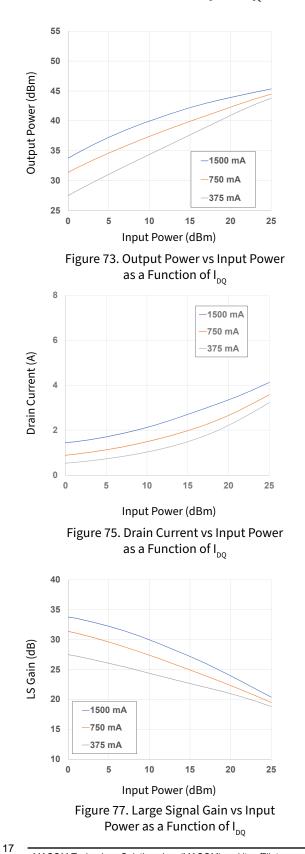


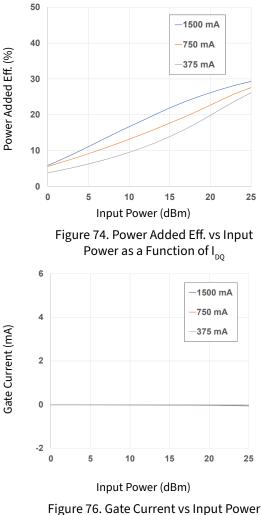
Figure 71. Gate Current vs Input Power as a Function of Voltage

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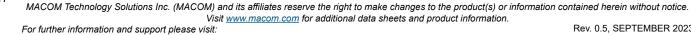


Test conditions unless otherwise noted: $V_D = 28 V$, $I_{DO} = 1500 mA$, CW, $P_{IN} = 23 dBm$, $T_{BASE} = +25 °C$





as a Function of I_{DO}

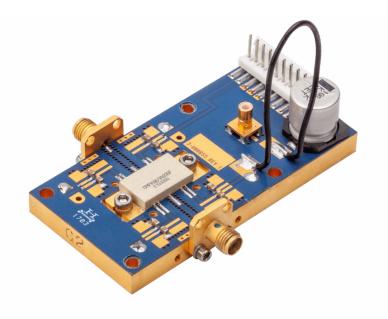




CMPA901A035F-AMP Evaluation Board Bill of Materials

Designator	Description	Qty
C15	CAP ELECT 100 UF 80 V AFK SMD	1
C16 - C23	CAP, 33000 PF, 0805, 100 V, X7R	8
R1, R2	RES 0.0 OHM 1/16 W 0402 SMD	2
J1, J2	CONN, SMA, PANEL MOUNT JACK, FLANGE, 4-HOLE, BLUNT POST, 20MIL	2
J4	CONN, SMB, STRAIGHT JACK RECEPTACLE, SMT, 50 OHM, Au PLATED	1
J3	HEADER RT>PLZ .1CEN LK 9POS	1
W1	WIRE, BLACK, 22 AWG ~ 1.50"	1
W2	WIRE, BLACK, 22 AWG ~ 1.75"	1
W3	WIRE, BLACK, 22 AWG ~ 3.0"	1
Q1	CMPA901A035F	1

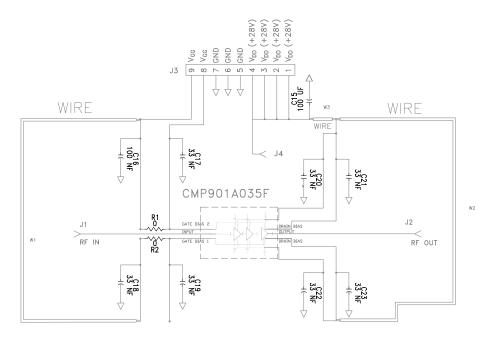
CMPA901A035F-AMP Evaluation Board Circuit



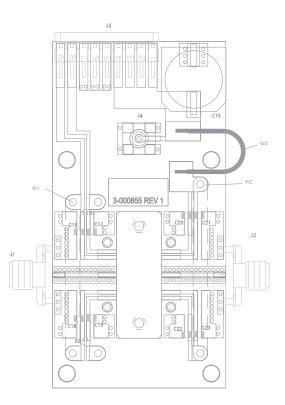
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CMPA901A035F-AMP Evaluation Board Schematic

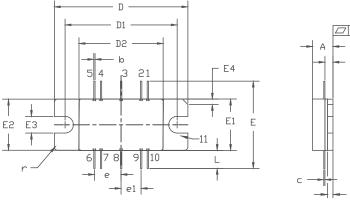


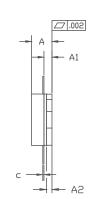
CMPA901A035F-AMP Evaluation Board Outline





Product Dimensions CMPA901A035F





PIN	1: GATE BIAS	6: DRAIN BIAS
	2: GATE BIAS	7: DRAIN BIAS
	3: RF IN	8: RF OUT
	4: GATE BIAS	9 DRAIN BIAS
	5: GATE BIAS	10: DRAIN BIAS
		11: SOURCE

NΠ	TES:	

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M - 1994.

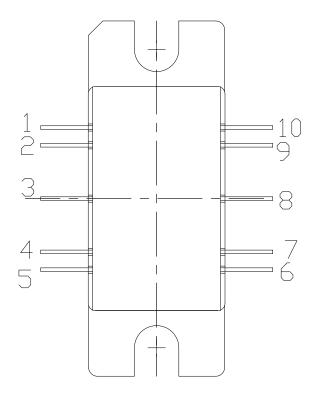
2. CONTROLLING DIMENSION: INCH.

3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020" BEYOND EDGE OF LID.

4. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF 0.008" IN ANY DIRECTION.

	INC	HES	MILLIMETERS		NOTES
DIM	MIN	МАХ	MIN	MAX	
Α	0.148	0.168	3.76	4.27	
A1	0.055	0.065	1.40	1.65	
A2	0.035	0.045	0.89	1.14	
b	0.01	TYP	0.254	TYP	10x
с	0.007	0.009	0.18	0.23	
D	0.995	1.005	25.27	25.53	
D1	0.835	0.845	21.21	21.46	
D2	0.623	0.637	15.82	16.18	
Е	0.653	TYP	16.59 TYP		
E1	0.380	0.390	9.65	9.91	
E2	0.380	0.390	9.65	9.91	
E3	0.120	0.130	3.05	3.30	
E4	0.035	0.045	0.89	1.14	45° CHAMFER
е	0.20) TYP	5.08	TYP	4x
e1	0.15) TYP	3.81	TYP	4x
L	0.115	0.155	2.92	3.94	10x
r	0.02	5 TYP	.635	TYP	Зx

Pin Number	Qty			
1	Gate Bias for Stage 1, 2 & 3			
2	Gate Bias for Stage 1, 2 & 3			
3	RF IN			
4	Gate Bias for Stage 1, 2 & 3			
5	Gate Bias for Stage 1, 2 & 3			
6	Drain Bias			
7	Drain Bias			
8	RF OUT			
9	Drain Bias			
10	Drain Bias			



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Part Number System

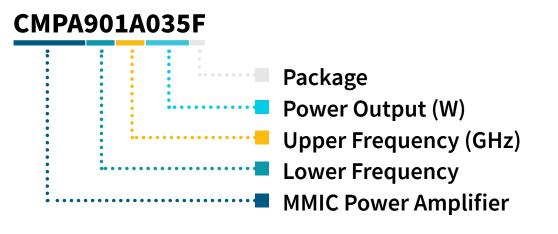


Table 1.

Parameter	Value	Units
Lower Frequency	9.0	GHz
Upper Frequency ¹	10.0	GHz
Power Output	35	W
Package	Flanged	-

Note:

¹Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

Table 2.

Character Code	Code Value
A	0
В	1
C	2
D	3
E	4
F	5
G	6
Н	7
J	8
К	9
Examples:	1 A = 10.0 GHz 2 H = 27.0 GHz

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Product Ordering Information

Order Number	Description	Unit of Measure	Image
CMPA901A035F	GaN HEMT	Each	CHIPSOLIDISE CHIPSOLIDISE
CMPA901A035F-AMP	Test Board with GaN MMIC Installed	Each	



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